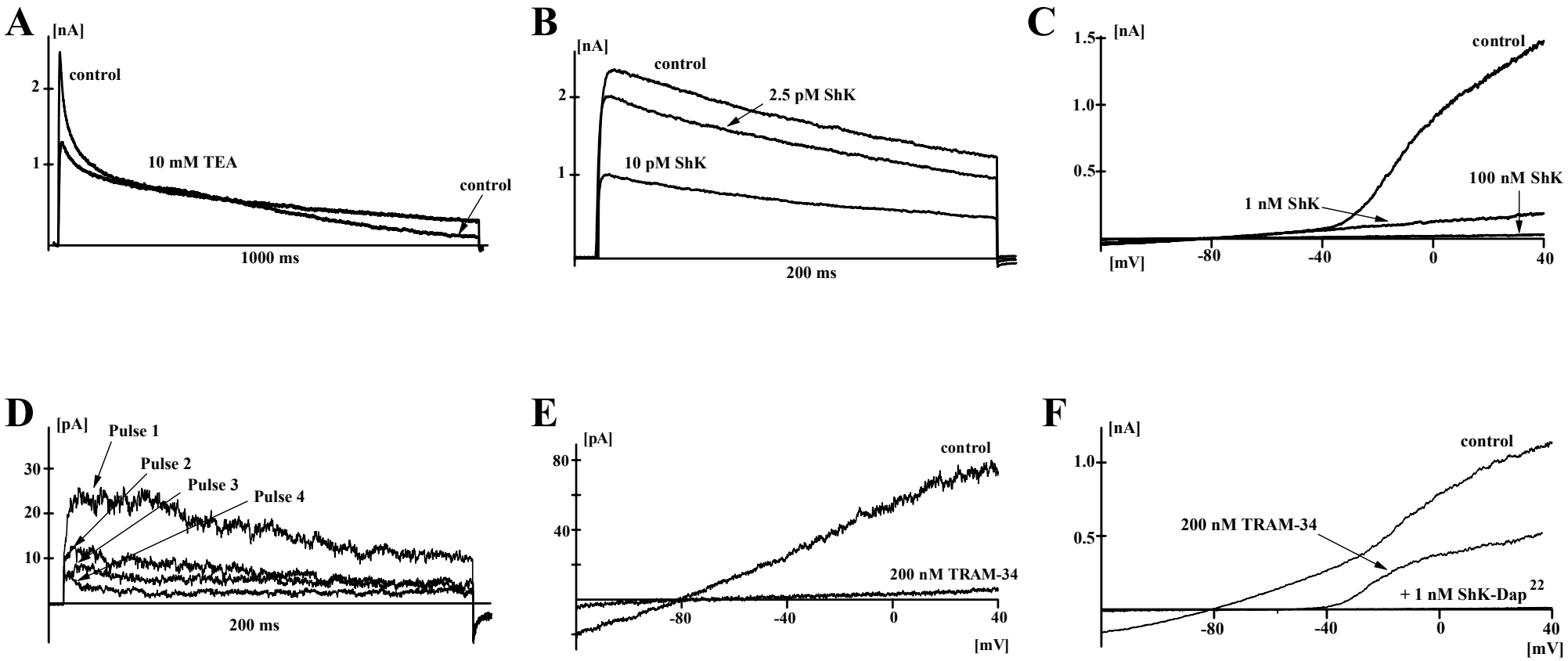
A
[nA]
2
1
control
10 mM TEA
control
1000 ms
B
[nA]
2
1
control
2.5 pM ShK
10 pM ShK
200 ms
C
1.5
[nA]
1.0
0.5
control
100 nM ShK
1 nM ShK
[mV]
-80
-40
0
40
D
[pA]
30
20
10
Pulse 1
Pulse 2
Pulse 3
Pulse 4
200 ms
E
[pA]
80
40
control
200 nM TRAM-34
-80
-40
0
40
[mV]
F
[nA]
1.0
0.5
control
200 nM TRAM-34
+ 1 nM ShK-Dap 22
-80
-40
0
40
[mV]